

CMOS Hex Buffer/Converters

1. Description

The CD4049UB and CD4050B are inverting and non-inverting hex buffers, respectively, and feature logic-level conversion using only one supply voltage (V_{CC}). The input-signal high level (V_{IH}) can exceed the V_{CC} supply voltage when these devices are used for logic-level conversions. These devices are intended for use as CMOS to DTL/TTL converters and can drive directly two DTL/TTL loads.

2. Features

- CD4049UB Inverting
- CD4050B Non-Inverting

- High Sink Current for Driving 2 TTL Loads
- High-To-Low Level Logic Conversion
- 100% Tested for Quiescent Current at 20V
- Maximum Input Current of $1\mu A$ at 18V Over Full Package Temperature Range; 100nA at 18V and 25°C
- 5V, 10V and 15V Parametric Ratings

3. Applications

- CMOS to DTL or TTL Hex Converters
- CMOS Current Sink or Source Drivers
- CMOS High-to-Low Logic Level Converters

4. Ordering Information

Type Number	Description	Package Type	Marking	Packing	SPQ
CD4049UBN		DIP-16	CD4049UB	Tube	
CD4049UBM		SOP-16	CD4049UB	Reel	
CD4050BN		DIP-16	CD4050B	Tube	
CD4050BM		SOP-16	CD4050B	Reel	

5. Pinouts

CD4049UB (TOP VIEW)	CD4050B (TOP VIEW)

6. Functional Block Diagrams

CD4049UB	CD4050B
<p>A — 3 —> 2 — G = \bar{A}</p>	<p>A — 3 —> 2 — G = A</p>
<p>B — 5 —> 4 — H = \bar{B}</p>	<p>B — 5 —> 4 — H = B</p>
<p>C — 7 —> 6 — I = \bar{C}</p>	<p>C — 7 —> 6 — I = C</p>
<p>D — 9 —> 10 — J = \bar{D}</p>	<p>D — 9 —> 10 — J = D</p>
<p>E — 11 —> 12 — K = \bar{E}</p>	<p>E — 11 —> 12 — K = E</p>
<p>F — 14 —> 15 — L = \bar{F}</p>	<p>F — 14 —> 15 — L = F</p>
<p>V_{CC} — 1 —</p> <p>V_{SS} — 8 —</p> <p>NC = 13</p> <p>NC = 16</p>	<p>V_{CC} — 1 —</p> <p>V_{SS} — 8 —</p> <p>NC = 13</p> <p>NC = 16</p>

7. Schematic Diagrams

CD4049UB IDENTICAL UNITS	CD4050B IDENTICAL UNITS

8. Absolute Maximum Ratings

		MIN	MAX	UNIT
Supply voltage	V _{CC} to V _{SS}	-0.5	20	V
DC input current, I _{IK}	Any one input		±10	mA
Lead temperature (soldering, 10 s)	SOIC, lead tips only		265	°C
Junction temperature, T _J			150	°C
Storage temperature, T _{stg}		-65	150	°C

9. Recommended Operating Conditions

		MIN	MAX	UNIT
T _A	Operating temperature	-55	125	°C

10. DC Electrical Specifications

PARAMETER	TEST CONDITIONS			LIMITS AT INDICATED TEMPERATURE (°C)							UNITS
								25			
	V _O (V)	V _{IN} (V)	V _{CC} (V)	-55	-40	85	125	MIN	TYP	MAX	
Quiescent Device Current I _{DD} (Max)	-	0,5	5	1	1	30	30	-	0.02	1	mA
	-	0,10	10	2	2	60	60	-	0.02	2	mA
	-	0,15	15	4	4	120	120	-	0.02	4	mA
	-	0,20	20	20	20	600	600	-	0.04	20	mA
Output Low (Sink) Current I _{OL} (Min)	0.4	0,5	4.5	3.3	3.1	2.1	1.8	2.6	5.2	-	mA
	0.4	0,5	5	4	3.8	2.9	2.4	3.2	6.4	-	mA
	0.5	0,10	10	10	9.6	6.6	5.6	8	16	-	mA
	1.5	0,15	15	26	25	20	18	24	48	-	mA
Output High (Source) Current I _{OH} (Min)	4.6	0,5	5	-0.81	-0.73	-0.58	-0.48	-0.65	-1.2	-	mA
	2.5	0,5	5	-2.6	-2.4	-1.9	-1.55	-2.1	-3.9	-	mA
	9.5	0,10	10	-2.0	-1.8	-1.35	-1.18	-1.65	-3.0	-	mA
	13.5	0,15	15	-5.2	-4.8	-3.5	-3.1	-4.3	-8.0	-	mA
Out Voltage Low Level V _{OL} (Max)	-	0,5	5	0.05	0.05	0.05	0.05	-	0	0.05	V
	-	0,10	10	0.05	0.05	0.05	0.05	-	0	0.05	V
	-	0,15	5	0.05	0.05	0.05	0.05	-	0	0.05	V
Output Voltage High Level V _{OH} (Min)	-	0,5	5	4.95	4.95	4.95	4.95	4.95	5	-	V
	-	0,10	10	9.95	9.95	9.95	9.95	9.95	10	-	V
	-	0,15	15	14.95	14.95	14.95	14.95	14.95	15	-	V
Input Low Voltage V _{IL} (Max) CD4049UB	4.5	-	5	1	1	1	1	-	-	1	V
	9	-	10	2	2	2	2	-	-	2	V
	13.5	-	15	2.5	2.5	2.5	2.5	-	-	2.5	V
Input Low Voltage V _{IL} (Max) CD4050B	0.5	-	5	1.5	1.5	1.5	1.5	-	-	1.5	V
	1	-	10	3	3	3	3	-	-	3	V
	1.5	-	15	4	4	4	4	-	-	4	V
Input High Voltage V _{IH} Min CD4049UB	0.5	-	5	4	4	4	4	4	-	-	V
	1	-	10	8	8	8	8	8	-	-	V
	1.5	-	15	12.5	12.5	12.5	12.5	12.5	-	-	V
Input High Voltage V _{IH} Min CD4050B	4.5	-	5	3.5	3.5	3.5	3.5	3.5	-	-	V
	9	-	10	7	7	7	7	7	-	-	V
	13.5	-	15	11	11	11	11	11	-	-	V
Input Current I _{IN} Max	-	0,18	18	±0.1	±0.1	±1	±1	-	±10 ⁻⁵	±0.1	mA

11. AC Electrical Specifications

PARAMETER	TEST CONDITIONS		LIMITS (ALL PACKAGES)		UNITS
	V _{IN}	V _{CC}	TYP	MAX	
Propagation Delay Time Low to High, t _{PLH} CD4049UB	5	5	60	120	ns
	10	10	32	65	ns
	10	5	45	90	ns
	15	15	25	50	ns
	15	5	45	90	ns
Propagation Delay Time Low to High, t _{PLH} CD4050B	5	5	70	140	ns
	10	10	40	80	ns
	10	5	45	90	ns
	15	15	30	60	ns
	15	5	40	80	ns
Propagation Delay Time High to Low, t _{PHL} CD4049UB	5	5	32	65	ns
	10	10	20	40	ns
	10	5	15	30	ns
	15	15	15	30	ns
	15	5	10	20	ns
Propagation Delay Time High to Low, t _{PHL} CD4050B	5	5	55	110	ns
	10	10	22	55	ns
	10	5	50	100	ns
	15	15	15	30	ns
	15	5	50	100	ns
Transition Time, Low to High, t _{TLH}	5	5	80	160	ns
	10	10	40	80	ns
	15	15	30	60	ns
Transition Time, High to Low, t _{THL}	5	5	30	60	ns
	10	10	20	40	ns
	15	15	15	30	ns
Input Capacitance, C _{IN} CD4049UB	-	-	15	22.5	pF
Input Capacitance, C _{IN} CD4050B	-	-	5	7.5	pF

12. Typical Performance Curves

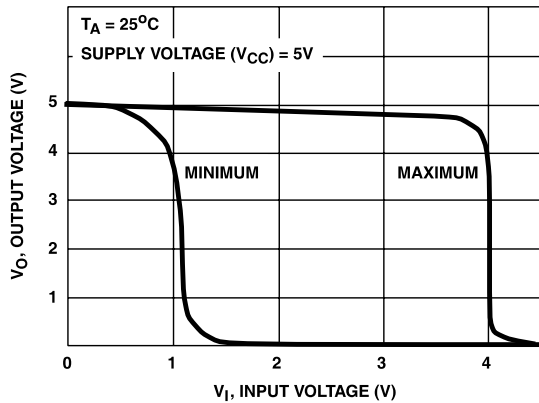


FIGURE 2. MINIMUM AND MAXIMUM VOLTAGE TRANSFER CHARACTERISTICS FOR CD4049UB

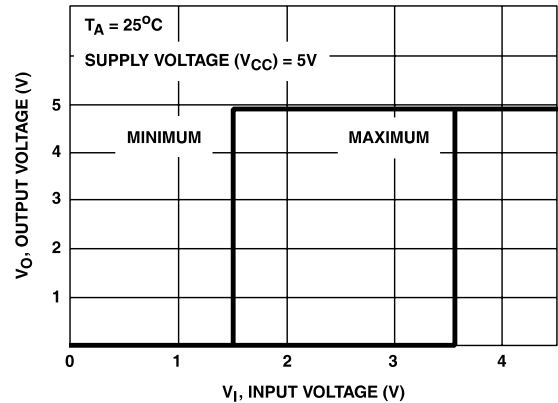


FIGURE 3. MINIMUM AND MAXIMUM VOLTAGE TRANSFER CHARACTERISTICS FOR CD4050B

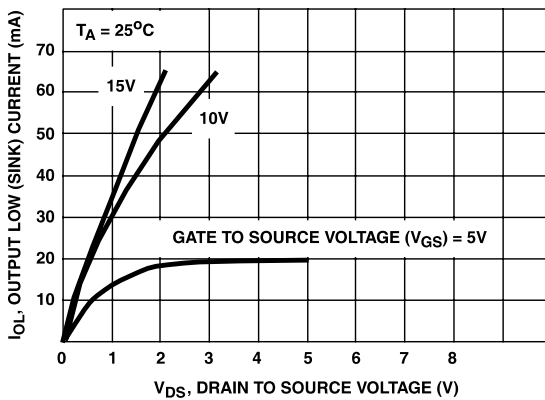


FIGURE 4. TYPICAL OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

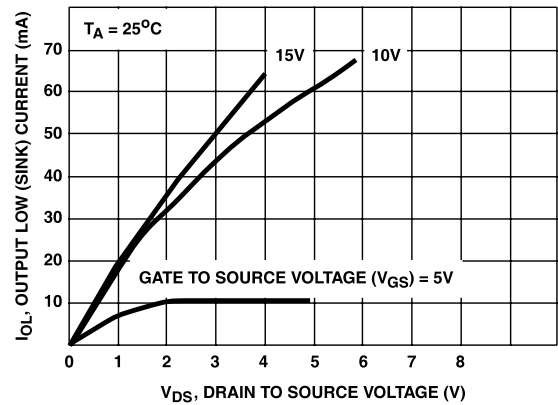


FIGURE 5. MINIMUM OUTPUT LOW (SINK) CURRENT DRAIN CHARACTERISTICS

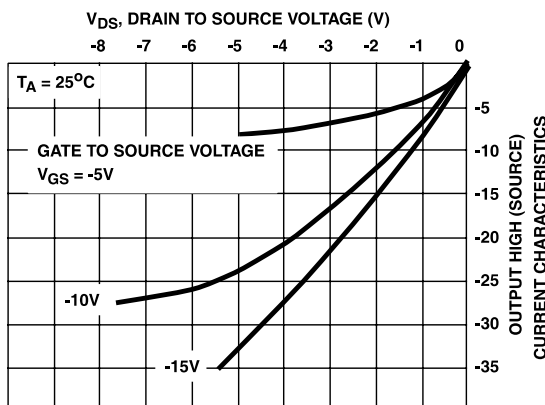


FIGURE 6. TYPICAL OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

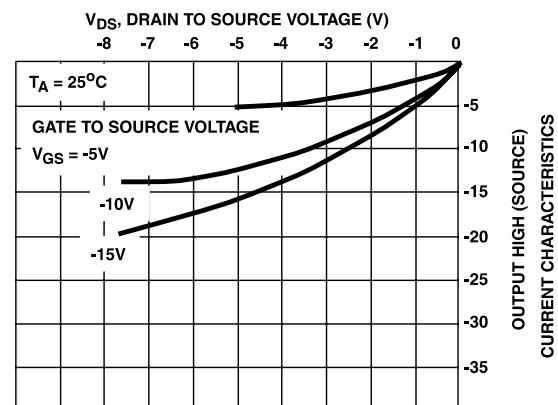


FIGURE 7. MINIMUM OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

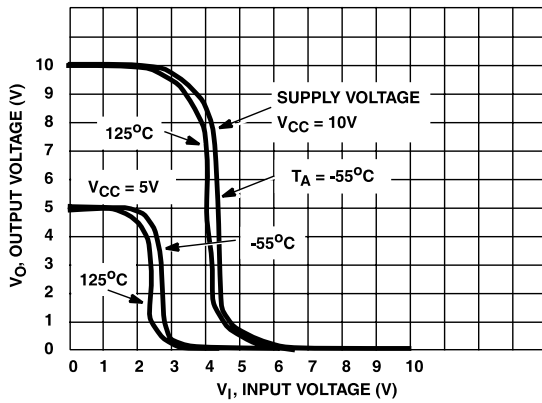


FIGURE 8. TYPICAL VOLTAGE TRANSFER CHARACTERISTICS AS A FUNCTION OF TEMPERATURE FOR CD4049UB

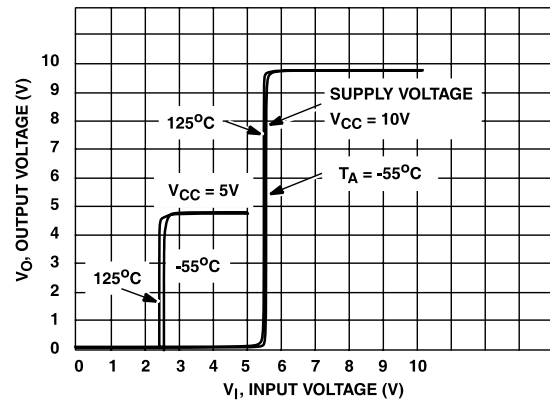


FIGURE 9. TYPICAL VOLTAGE TRANSFER CHARACTERISTICS AS A FUNCTION OF TEMPERATURE FOR CD4050B

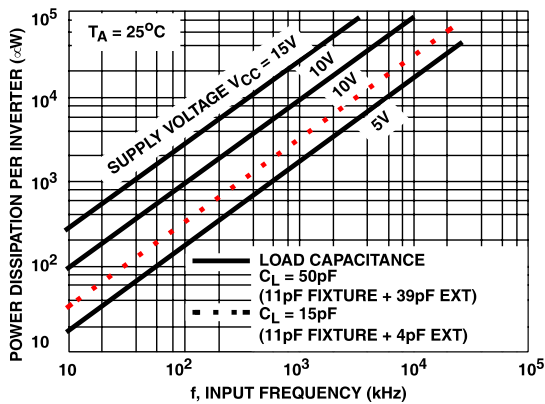


FIGURE 10. TYPICAL POWER DISSIPATION vs FREQUENCY CHARACTERISTICS

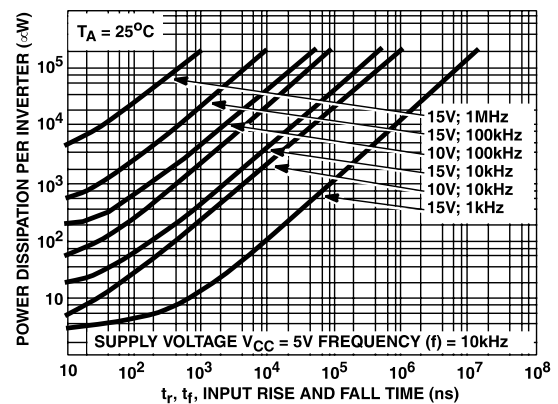


FIGURE 11. TYPICAL POWER DISSIPATION vs INPUT RISE AND FALL TIMES PER INVERTER FOR CD4049UB

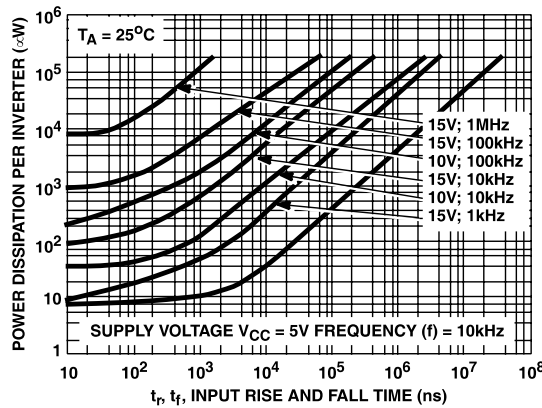


FIGURE 12. TYPICAL POWER DISSIPATION vs INPUT RISE AND FALL TIMES PER INVERTER FOR CD4050B

13. Test Circuits

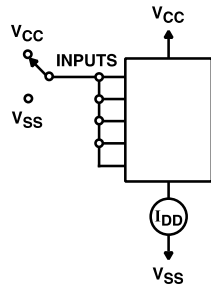
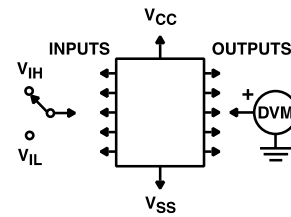
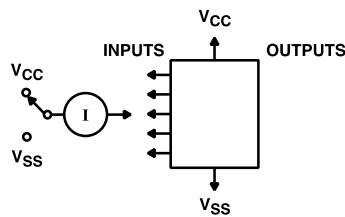


FIGURE 13. QUIESCENT DEVICE CURRENT TEST CIRCUIT



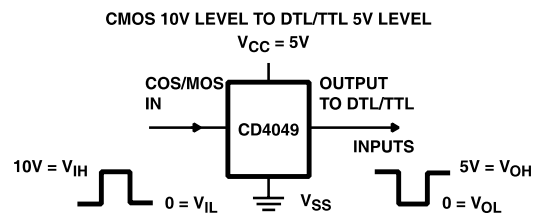
NOTE: Test any one input with other inputs at V_{CC} or V_{SS} .

FIGURE 14. INPUT VOLTAGE TEST CIRCUIT



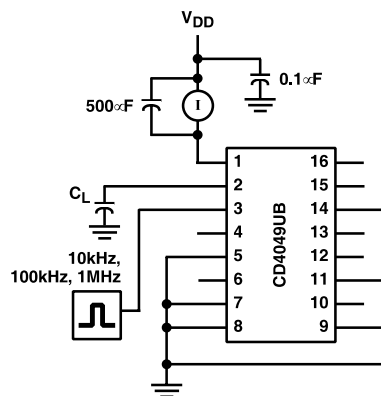
NOTE: Measure inputs sequentially, to both V_{CC} and V_{SS} connect all unused inputs to either V_{CC} or V_{SS} .

FIGURE 15. INPUT CURRENT TEST CIRCUIT



In Terminal - 3, 5, 7, 9, 11, or 14
 Out Terminal - 2, 4, 6, 10, 12 or 15
 V_{CC} Terminal - 1
 V_{SS} Terminal - 8

FIGURE 16. LOGIC LEVEL CONVERSION APPLICATION

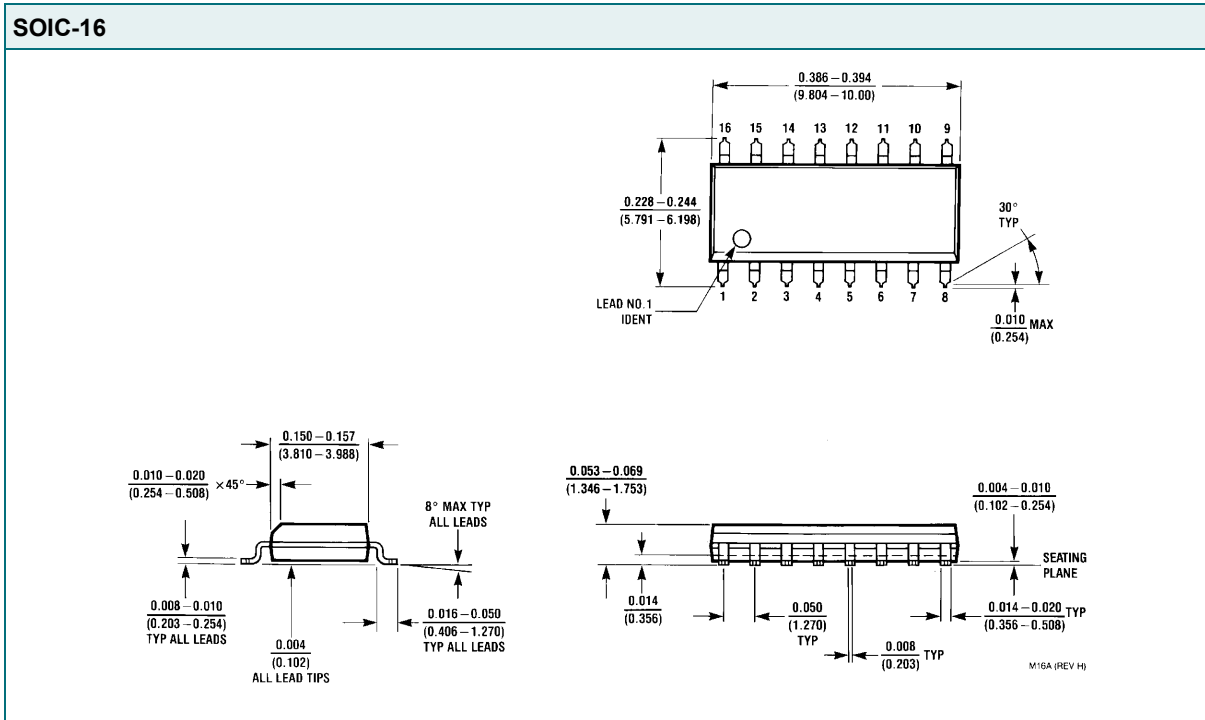


C_L INCLUDES FIXTURE CAPACITANCE

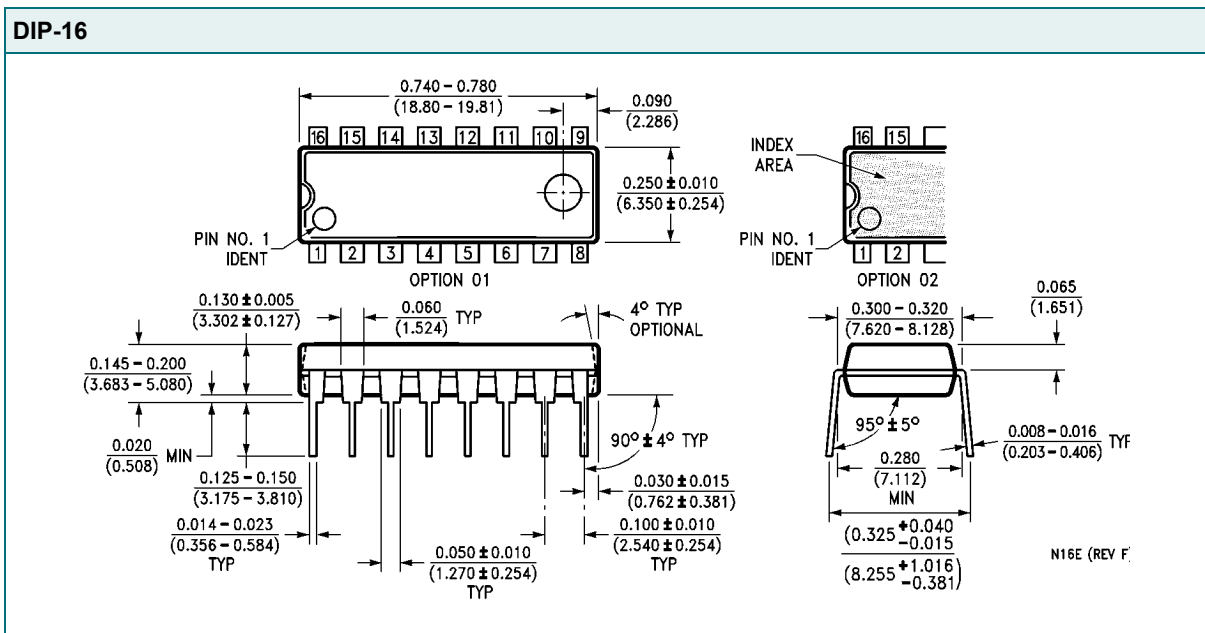
FIGURE 17. DYNAMIC POWER DISSIPATION TEST CIRCUITS

14. Package outlines

SOIC-16



DIP-16



15. Disclaimers

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